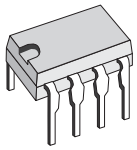
SGS-THOMSON MICROELECTRONICS

TEA5170

SWITCH MODE POWER SUPPLY SECONDARY CIRCUIT

- INTERNAL PWM SIGNAL GENERATOR
- POWER SUPPLY WIDE RANGE 4.5V – 14.5V
- SOFT START
- REFERENCE VOLTAGE 2V ± 5%
- WIDE FREQUENCY RANGE 250kHz
- MINIMUM OUTPUT PULSE WIDTH 500nS
- MAXIMUM PRESET DUTY CYCLE
- SYNCHRONIZATION WINDOW
- OUTPUT SWITCH
- UNDERVOLTAGE LOCKOUT
- FREQUENCY RANGE WITH SYNCHRONIZATION 64kHz



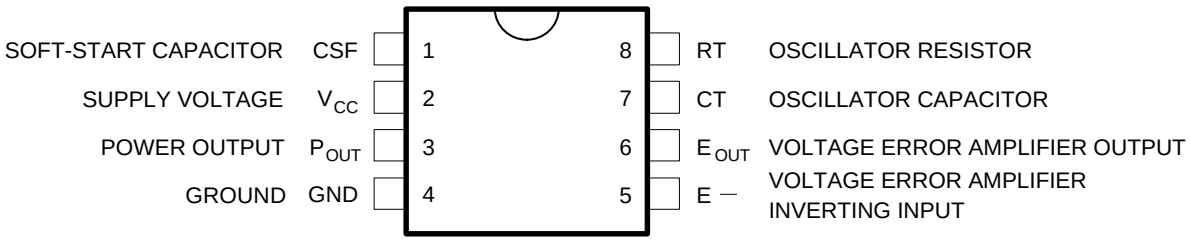
DIP8
(Plastic Package)

ORDER CODE : TEA5170

DESCRIPTION

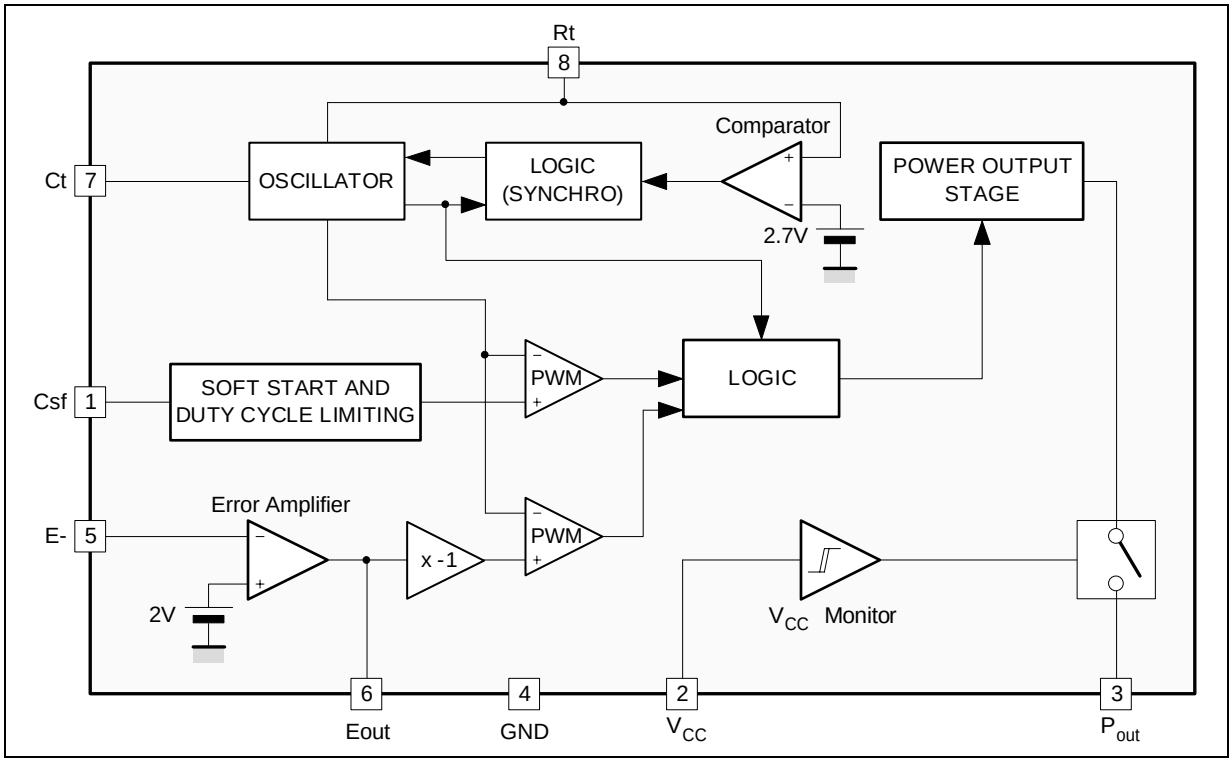
The TEA5170 is designed to work in the secondary part of an off-line SMPS, sending pulses to the slaved TEA2260/61 which are located on the primary side of the main transformer. An accurate regulated voltage is obtained by duty cycle control. The TEA5170 can be externally synchronized by higher or lower frequency signal, then it could be used in applications like TV set ones. For more details, refer to application note AN408/0591.

PIN CONNECTIONS



5170-01.EPS

BLOCK DIAGRAM



ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V_{CC}	Supply Voltage	15	V
T_j	Operating Junction Temperature	150	°C
T_{stg}	Storage Temperature Range	– 40, + 150	°C

5170-01.TBL

THERMAL DATA

Symbol	Parameter	Value	Unit
$R_{th\ (j-a)}$	Junction-ambient Thermal Resistance	90	°C/W

5170-02.TBL

RECOMMANDED OPERATING CONDITIONS

Symbol	Parameter	Min.	Typ.	Max.	Unit
V_{CC}	Power Supply Voltage	5		14	V
RT	Timing Resistor	47		180	kΩ
CT	Timing Capacitor	0.12		1.8	nF
Fosc	Oscillator Frequency	12		250	kHz
Fsy	Synchro Frequency	12		64	kHz
T_{amb}	Operating Ambient Temperature	– 20		70	°C
VRT	Voltage on Pin RT (8)			7	Volt
VCT	Current on Pin CT (1)			100	µA
I_{SOURCE}	Output Current		30	60	mA

5170-03.TBL

ELECTRICAL CHARACTERISTICS (T_A = 25°C, V_{CC} = 12V, unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
OSCILLATOR						
TA	Free Period	RT = 100kΩ ± 0% CT = 1.2nF ± 0%, Vcc = 12V	60.40	65.60	70.80	µS
TB		RT = 100kΩ ± 0% CT = 560pF ± 0%, Vcc = 12V	29.18	31.70	34.22	µS
ΔF_{OSC} (T)	Frequency drift due to ambient temperature variation from 0°C to 70°C $\frac{F_{OSC}(70^oC) - F_{OSC}(0^oC)}{70^oC \times F_{OSC}(25^oC)}$	RT = 100kΩ ± 0% CT = 1.2nF ± 0%, Vcc = 12V		0.01		%/°C
ΔF_{OSC} (V_{CC})	Frequency drift due to V_{CC} variation from 5V to 12V $\frac{F_{OSC}(12V) - F_{OSC}(5V)}{7V \times F_{OSC}(12V)}$	RT = 100kΩ ± 0% CT = 1.2nF ± 0%		0.07		%/V
ERROR VOLTAGE AMPLIFIER (V_{CC} = 12V)						
Ibias	Input Bias Current	Ein = 2V	0	0.2	1	µA
Gvol	Voltage Gain			80		dB
GB	Gain Bandwidth			2		MHz
	Slew Rate			2		V/µs
INTERNAL VOLTAGE REFERENCE						
V_{REF}	Voltage Reference	Using the voltage error amplifier as a follower	1.9	2	2.1	V
ΔV_{REF} (V_{CC})	Line Regulation $\frac{V_{REF}(12V) - V_{REF}(5V)}{7V}$	V_{CC} = 5V to 12V	– 3	0.4	3	mV/V
ΔV_{REF} (T)	V_{REF} drift with temperature $\frac{V_{REF}(70^oC) - V_{REF}(0^oC)}{70^oC}$	T_A = 0°C to 70°C		0.2		mV/°
$T_{ON\ MIN}$						
$T_{ONMIN\ A}$	Minimum Duty Cycle	Ct = 1.2nF ± 0% Rt = 100kΩ ± 0%	1.77	2.53	3.29	µs
$T_{ONMIN\ B}$	Minimum Duty Cycle	Ct = 560pf ± 0% Rt = 100kΩ ± 0%	1.04	1.49	1.94	µs
POWER OUTPUT STAGE						
V_{POUTH}	Output High Level	I_{load} = 1mA	6.3	6.9	7.5	V
V_{POUTL}	Output Low Level	I_{load} = – 1mA	0.5	0.8	1.1	V
I_{SINK}	Sink Current	V_{POUT} = 3V	30	60	190	mA
I_{SOURCE}	Source Current	V_{POUT} = 3V	30	110	190	mA
SYNCHRONISATION						
$F_{trig\ Max}$	Maximum Synchro Frequency		64			kHz
V_{trig}	Synchro Triggering Threshold			2.7	3	V
T_{trigp}	Synchro Triggering Pulse Width	at VRT = 2.7Volt (fig 5)	800			nS
Wtrig +	Positive Triggering Window $\frac{T_{trig+} - T_O}{T_O}$	CT = 1.2nF ± 0% RT = 100kΩ ± 0%	25	35	40	%
Wtrig –	Negative Triggering Window $\frac{T_O - T_{trig-}}{T_O}$	CT = 1.2nF ± 0% RT = 100kΩ ± 0%	9	29	42	%
SOFT START						
I_{csf}	*Csf Load Current	V_{csf} = 1V	2.5	3.7	6	µA
Donmax	Maximum Duty Cycle	V_{cs} > 2.5V, V_{CC} = 12V CT = 1.2nf ± 0% RT = 100kΩ ± 0%	60	78	95	%

5170-04.TBL

*Csf is a high impedance capacitor

ELECTRICAL CHARACTERISTICS (T_A = 25°C, V_{CC} = 12V, unless otherwise specified) (continued)

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
V_{CC} MONITOR						
V_{START}	Turn-on Threshold		3.60	4	4.40	V
V_{HYST}	Hysteresis Voltage		100			mV
V_{STOP}	Turn-off Threshold		3.50			V
TOTAL DEVICE						
I_{CC}	Supply Current	RT = 100kΩ ± 0%, CT = 1.2nf ± 0% No Load on Pin 3, V_{CC} = 12V	7	12	25	mA

5170-05.TBL

GENERAL DESCRIPTION

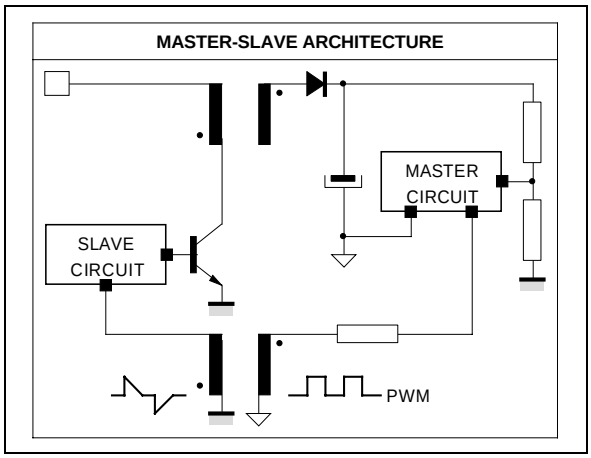
The TEA5170 takes place in the secondary part of an isolated off-line SMPS. During normal mode operation, it sends pulses to the slave circuit located in the primary side (TEA2164, TEA2260/61) through a pulse transformer to achieve a very precisely regulated voltage by duty cycle control.

The main blocs of the circuit are :
- an error voltage amplifier
- an RC oscillator
- an output stage
- a V_{CC} monitor
- a voltage reference bloc
- a pulse width modulator
- two logic blocs
- a soft start and Duty cycle limiting bloc

PRINCIPLE OF OPERATION

The TEA5170 sends pulses continuously to the slave circuit in order to insure a proper behaviour of the primary side.
- According to this, the output duty cycle is varying between $D_{ON\ (min.)}$ (0.05) and $D_{ON\ (max.)}$ (0.75) : then even in case of open load, pulses are still sent to the slave circuit.

Figure 1 : Basic Concept

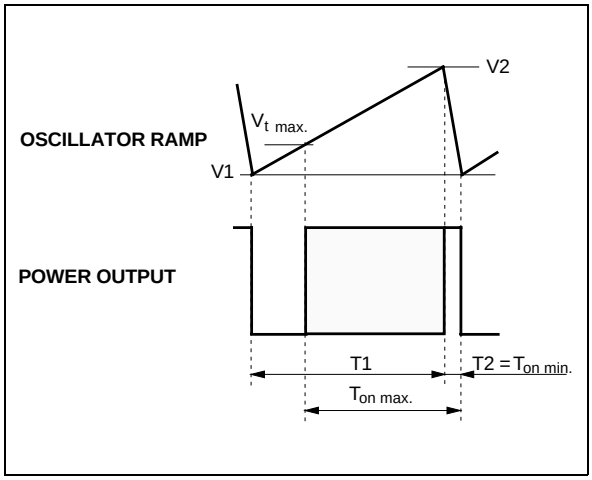


5170-03.EPS

ASYNCHRONIZED MODE (Figure 2)

The regulated voltage image is compared to 2V vol-tage reference. The error voltage amplifier output and the RC oscillator voltage ramp are applied to the internal Pulse Width Modulator Inputs.
The PWM logic Output is connected to a logic bloc which behaves like a RS latch, sets by the PWM output and resets when Ct downloading occurs. Finally, the push-pull output bloc delivers square wave signal whom output leading edge occurs during Ct uploading time, and output trailing edge at Ct downloading time end. The duty cycle is limited to 75% of oscillator period as maximum value and to Ct downloading time/oscillator period as minimum value (Figure 2).

Figure 2

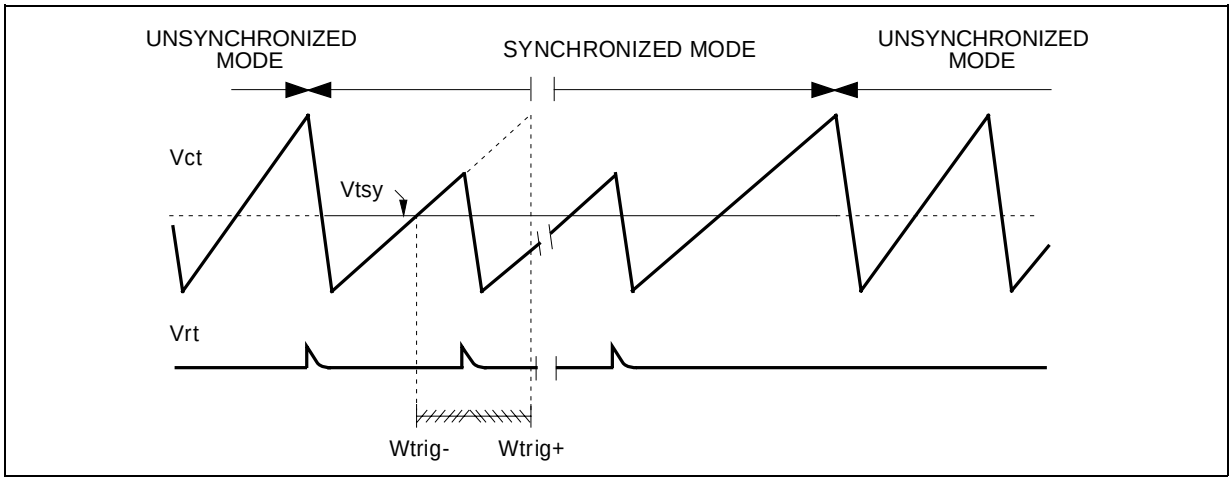


5170-04.EPS

SYNCHRONIZED MODE (see Figure 3)

The TEA5170 will enter the Synchronized Mode when it receives one pulse through Rt during Ct discharge.
At that time Ct charging current will be multiplied by 0.75 and period will increase up to To x 1.26.
A pulse occuring during the synchro window, commands the Ct downloading. If none, the TEA5170 will return to normal mode at the end of the period.

Figure 3



Remark : In case of an application between TEA5170 and TEA2164, to optimize the synchronization windows of these circuits, the following relations have to be used : $T_m = \frac{T_{SYNC}}{1.06} T_e = \frac{T_m}{1.223}$
with T_e : Free period of the TEA2164 oscillator, and T_m : Free period of the TEA5170 oscillator.

BLOCK DESCRIPTION

The error voltage amplifier inverting-input and output are accessible to use different feed-back network and allowing parasitic filtering network. The non-inverting input is internaly connected to 2V reference voltage.
The RC oscillator is designed to work at high frequency (up to 250kHz). R_T sets the capacitor charging current Io = $2/R_T$.
The capacitor C_T is loaded from $V_1 \approx 1V$ to $V_2 = 2V$ during $T1 = \frac{C_T R_T}{1.985}$ and then down loaded through an integrated resistor $R_2 \approx 1k\Omega$ during $T_2 = 1300\ C_T$
The ramp is used to limit the duty cycle. Then the maximum duty cycle is

$$DONMAX = \frac{1}{T1 + T2} (0.73\,T1 + T2)$$

The output level is V_{CC} independant when V_{CC} is over 8V.
The V_{CC} monitoring switches the circuit on when V_{CC} is over 4V and switches it off when under 3.8V. This function insures a proper starting procedure (made by the primary side circuit).

SYNCHRONIZATION

(see Figures 4 and 5)

Figure 4 : Triggering Schematic

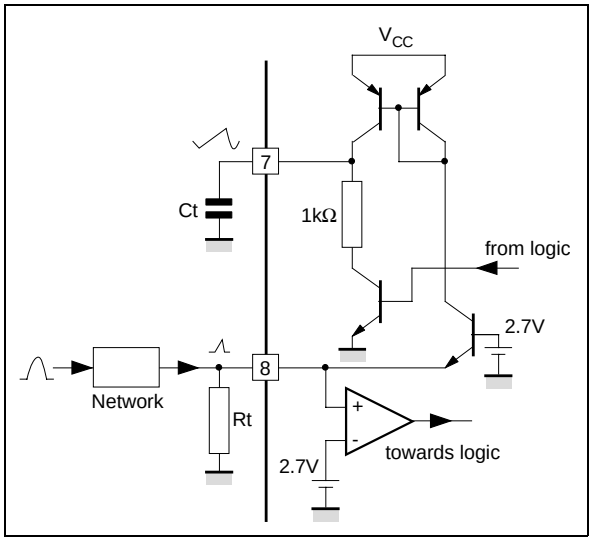
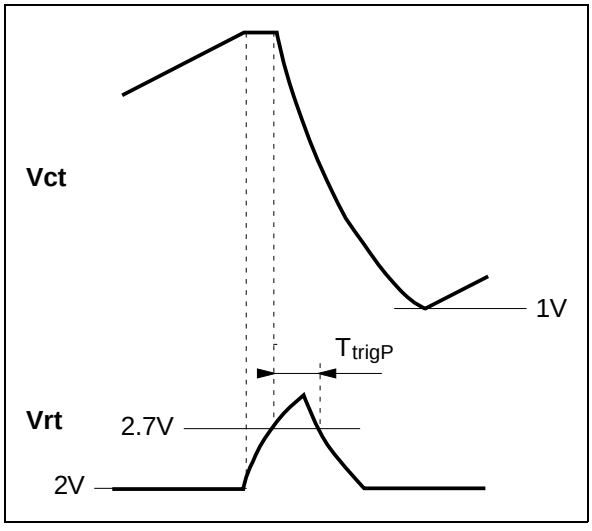


Figure 5 : Typical Waveforms



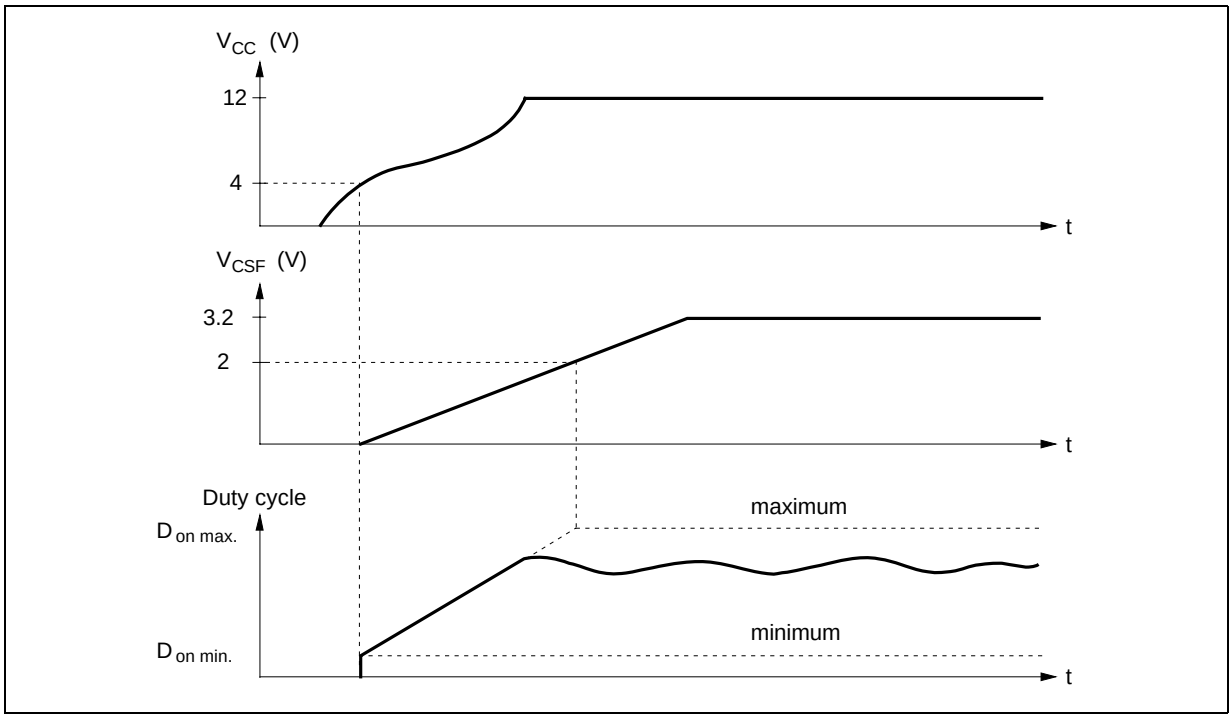
STARTING

When V_{CC} is under 4V, output pulses are not allowed and the slave circuit keeps its own mode. When V_{CC} is going over 4V, output pulses are sent via the pulse transformer (or an optical device) to the slave circuit which is synchronizing and entering the slaved mode. Output pulses can be shut down only if V_{CC} goes below 3.8 Volt.

SOFT START

Using Csf, it is possible to make a soft start sequence. When V_{CC} grows from 0V to 4V, voltage on Csf equals 0V. When V_{CC} is higher than 4V, Csf is loaded by a 3.7µA current, then TonMAX (Vcsf) will vary linearly from Tonmin to Tonmax according to Csfst bias.
When V_{CC} will go low (3.8 Volt threshold), Csf will be downloaded by an internal transistor.

Figure 6 : Soft-Start Sequence



POWER OUTPUT STAGE

Figure 7 : Electrical Schematic

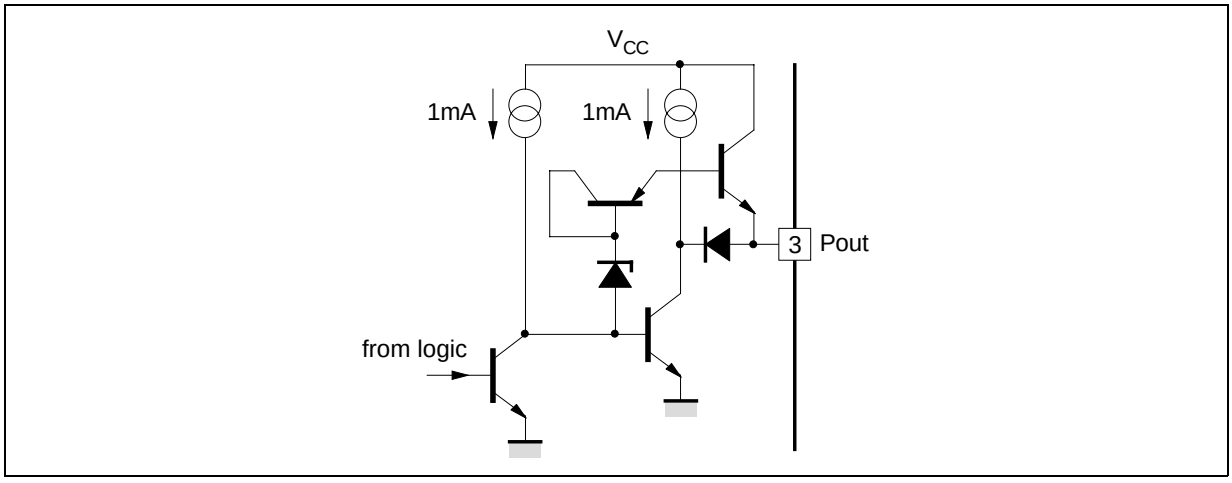


Figure 8

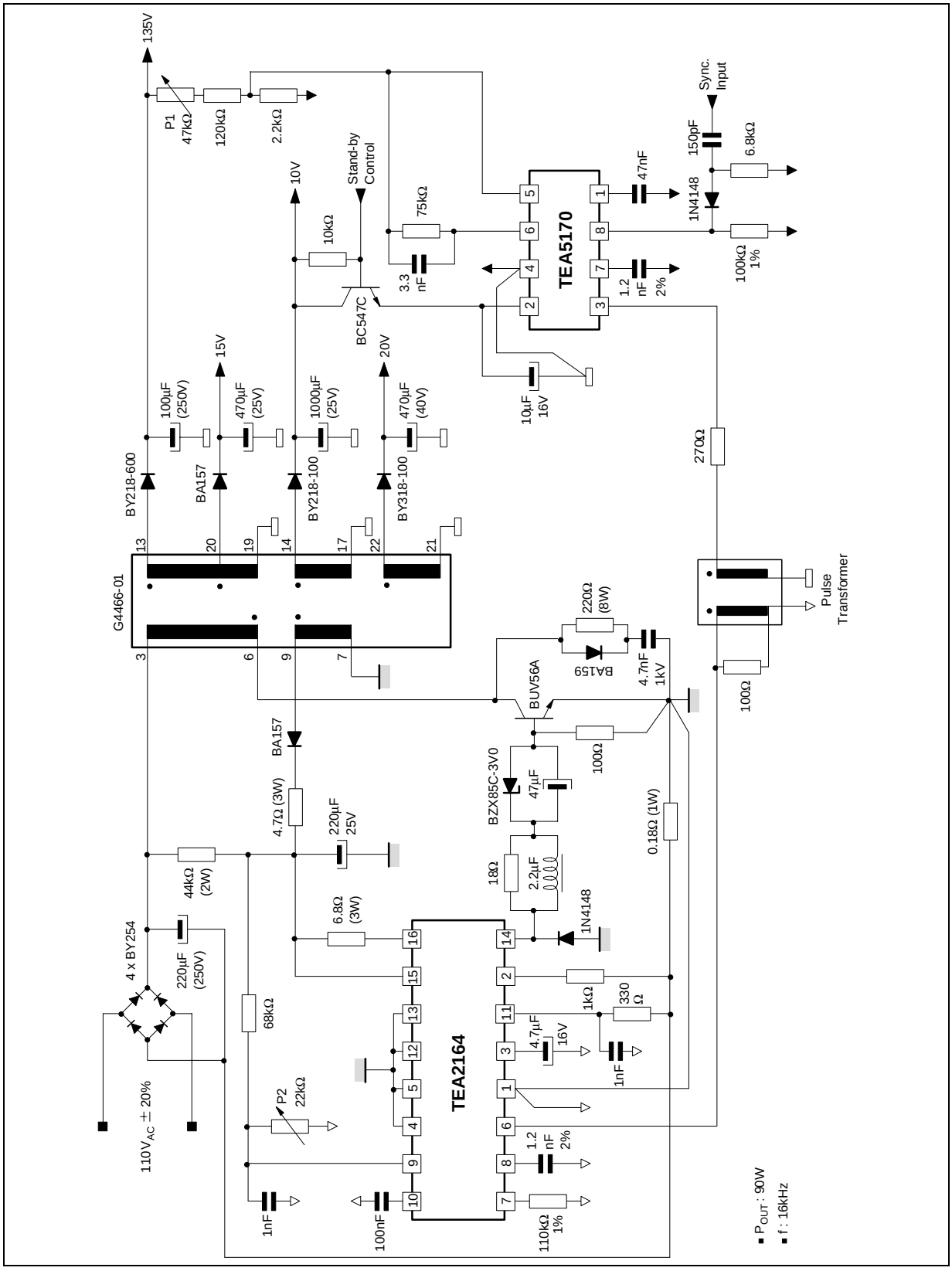
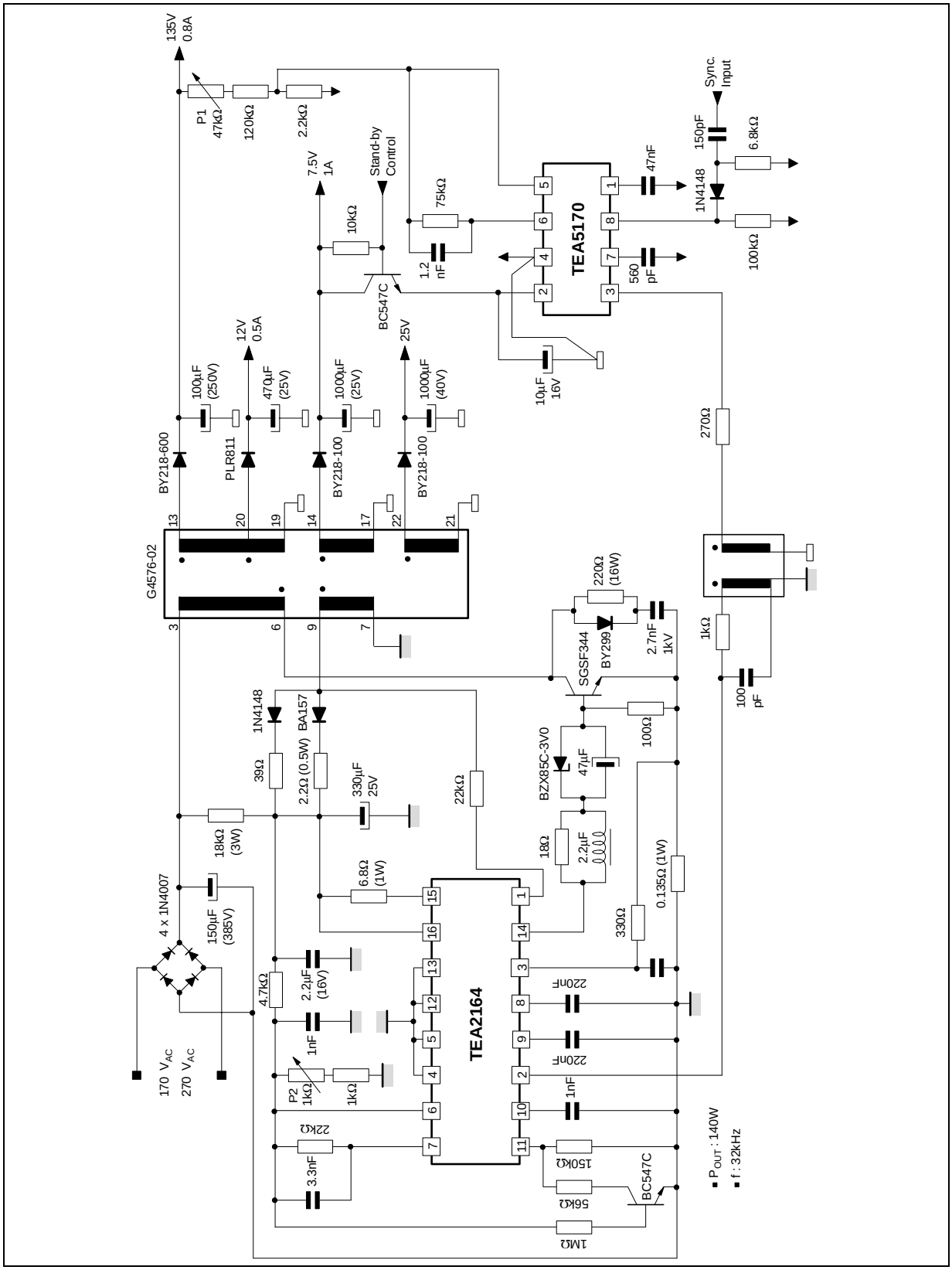
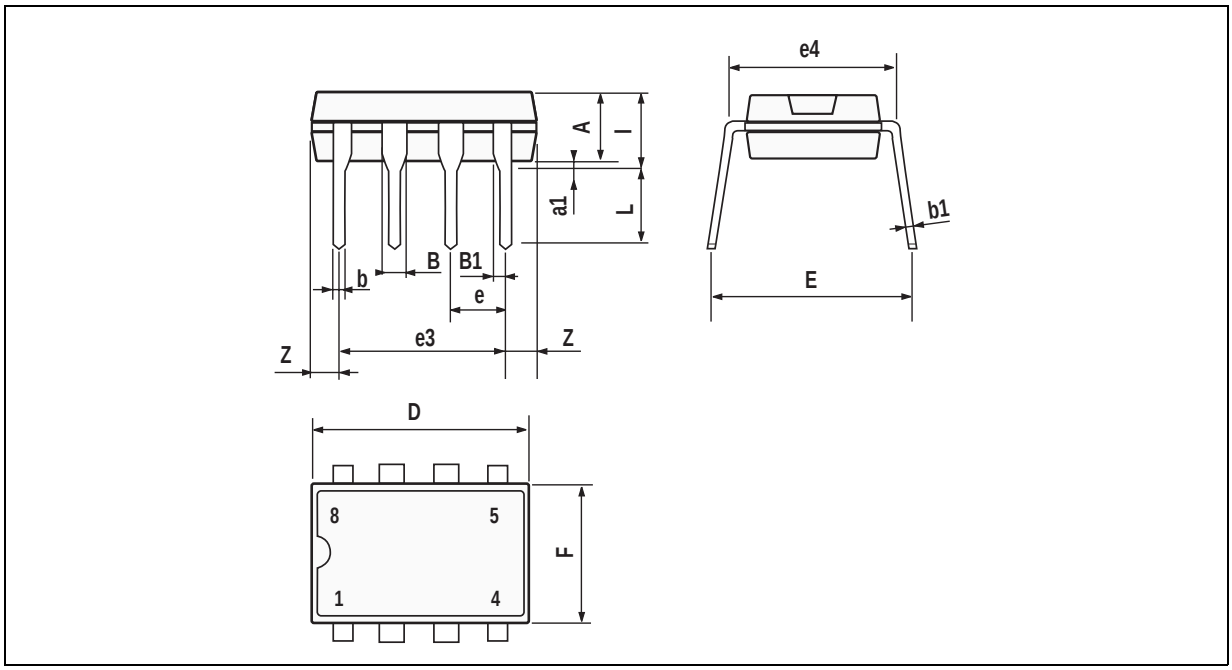

135V
P1
47kΩ
120kΩ
2.2kΩ
Stand-by Control
10V
10kΩ
75kΩ
3.3 nF
BC547C
TEA5170
Sync. Input
150pF
6.8kΩ
1N4148
47nF
100kΩ 1%
1.2 nF 2%
10µF 16V
15V
20V
100µF (250V)
470µF (25V)
1000µF (25V)
470µF (40V)
BY218-600
BA157
BY218-100
BY318-100
270Ω
G4466-01
Pulse Transformer
220Ω (8W)
BA159
4.7nF 1kV
BUV56A
100Ω
BA157
4.7Ω (3W)
220µF 25V
BZX85C-3V0
47µF
0.18Ω (1W)
44kΩ (2W)
18Ω
2.2µF
6.8Ω (3W)
1N4148
4 x BY254
220µF (250V)
68kΩ
1kΩ
330 Ω
4.7µF 16V
1nF
TEA2164
P2
22kΩ
1.2 nF 2%
110kΩ 1%
100nF
110V$_{AC}$ ± 20%
▪ P_{OUT} : 90W
▪ f : 16kHz
5170-10.EPS

Figure 9


135V 0.8A
P1 47kΩ
120kΩ
2.2kΩ
7.5V 1A
Stand-by Control
10kΩ
75kΩ
1.2 nF
BC547C
TEA5170
47nF
560 pF
Sync. Input
150pF
6.8kΩ
1N4148
100kΩ
12V 0.5A
25V
100µF (250V)
470µF (25V)
1000µF (25V)
1000µF (40V)
10µF 16V
270Ω
BY218-600
PLR811
BY218-100
BY218-100
G4576-02
220Ω (16W)
SGSF344
BY299
2.7nF 1kV
1kΩ
100 pF
1N4148
BA157
39Ω
2.2Ω (0.5W)
330µF 25V
22kΩ
BZX85C-3V0
47µF
100Ω
18kΩ (3W)
18Ω
2.2µF
0.135Ω (1W)
6.8Ω (1W)
330Ω
4 x 1N4007
150µF (385V)
TEA2164
4.7kΩ
2.2µF (16V)
220nF
1nF
220nF
P2 1kΩ
1kΩ
1nF
22kΩ
3.3nF
150kΩ
56kΩ
BC547C
1MΩ
170 V_{AC}
270 V_{AC}
P_{OUT} : 140W
f : 32kHz
5170-11.EPS

PACKAGE MECHANICAL DATA

8 PINS - PLASTIC DIP



PM-DIP8.EPS

Dimensions	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A		3.32			0.131	
a1	0.51			0.020		
B	1.15		1.65	0.045		0.065
b	0.356		0.55	0.014		0.022
b1	0.204		0.304	0.008		0.012
D			10.92			0.430
E	7.95		9.75	0.313		0.384
e		2.54			0.100	
e3		7.62			0.300	
e4		7.62			0.300	
F			6.6			0260
i			5.08			0.200
L	3.18		3.81	0.125		0.150
Z			1.52			0.060

DIP8.TBL

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